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We have performed angle-resolved photoemission spectroscopy of AlB₂ which is isostructural to hightemperature superconductor $MgB₂$. Using soft-x-ray photons, we accurately determined the three-dimensional bulk band structure and found a highly anisotropic Dirac-cone band at the *K* point in the bulk hexagonal Brillouin zone. This band disperses downward on approaching the *H* point while keeping its degeneracy at the Dirac point, producing a characteristic Dirac nodal line along the *KH* line. We also found that the band structure of AlB_2 is regarded as a heavily electron-doped version of MgB_2 and is therefore well suited for fully visualizing the predicted Dirac nodal line. The present results suggest that the $(A_1Mg)B_2$ system is a promising platform for studying the interplay among the Dirac nodal line, carrier doping, and possible topological superconducting properties.

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Topological semimetals (TSMs) host a novel quantum state of matter distinct from well-known topological insulators with a finite bulk band gap and metallic Dirac-cone surface states. TSMs are characterized by the band crossing between bulk valence band and conduction band at discrete momentum (*k*) point(s) in the three-dimensional (3D) bulk Brillouin zone (BZ) , as realized in 3D Dirac semimetals $(DSMs)$ (e.g., Na₃Bi and $Cd₃As₂$) [\[1–6\]](#page-3-0) with fourfold degenerated Dirac nodes and Weyl semimetals (WSMs) (e.g., TaAs family) [\[7–11\]](#page-4-0) possessing pairs of twofold degenerated Weyl nodes. Such unconventional band crossings create various exotic physical properties such as chiral anomaly, extremely high mobility, and gigantic linear magnetoresistance $[12-20]$. There is another category of TSMs characterized by the band crossing along a one-dimensional curve in the *k* space (nodal line), called topological nodal-line semimetals (TNLSMs). It is theoretically proposed that TNLSMs exhibit unique physical properties such as a flat Landau level, long-range Coulomb interaction, and unusual charge polarization and orbital magnetism [\[21–24\]](#page-4-0). In contrast to the point node, the nodal line can have various shapes in *k* space depending on the details of the band structure and the type of symmetry protecting the nodes, as highlighted by a twofold Weyl nodal ring [\[25,26\]](#page-4-0), fourfold Dirac ring [\[27\]](#page-4-0), nodal link [\[28,29\]](#page-4-0), and nodal net [\[30–32\]](#page-4-0).

A useful approach to realize such exotic nodal structures is to utilize the band inversion, as demonstrated by the discovery of nodal rings in PbTaSe₂ [\[33\]](#page-4-0), CaAgAs [\[34\]](#page-4-0), and $(Zr/Hf)SiS$ [\[35–37\]](#page-4-0). However, TNLSMs so-far discovered are characterized by the crossing of energy bands originating from heavy elements such as transition-metal *d* bands, consequently leading to a finite spin-orbit-gap opening which masks the genuine low-energy properties of nodal fermions. To truly realize the nodal-line-related physical properties, it is important to search for materials which have a nodal structure with a relatively weak spin-orbit coupling (SOC).

In this regard, AIB_2 is one of most suitable materials because the energy bands near the Fermi level (E_F) are composed of only *s* and *p* orbitals of light elements (Al and B). As shown in Fig. $1(a)$, AlB₂ is isostructural to well-known hightemperature superconductor $MgB₂$, consisting of alternatively stacking honeycomb B layers and triangular Al lattices. A first-principles band calculation suggests that AIB_2 has a linear band crossing (Dirac cone) which arises from the B sublattice at the *K* point in the bulk BZ [\[38\]](#page-4-0), as in the case of graphene. Due to analogy with multilayer graphene, the band degeneracy at the Dirac point is expected to extend along the *kz* direction and form a Dirac nodal line (DNL) along the *KH* high-symmetry line [\[39\]](#page-4-0) [see Fig. [1\(b\)\]](#page-1-0). A similar prediction is also made for isostructural $Mg_{\rm B_2}$ [\[40\]](#page-4-0). It is therefore urgently required to experimentally establish the DNL in AlB_2 -type materials and clarify its possible link to the exotic physical properties.

In this Rapid Communication, we report angle-resolved photoemission spectroscopy (ARPES) of $AIB₂$ single crystal. By utilizing bulk-sensitive soft-x-ray photons from synchrotron radiation, we experimentally established the bulk valence band structure in the 3D bulk BZ and found a highly anisotropic Dirac-cone energy band in the $k_x - k_y$ plane which disperses along the k_z direction. This band keeps the degeneracy along the *KH* line, producing a characteristic DNL. We discuss implications of the present results by comparing with first-principles band-structure calculations and other topological nodal-line materials.

High-quality single crystals of $AIB₂$ were grown by the Al-flux method. ARPES measurements were performed with a Scienta-Omicron SES2002 electron analyzer with energytunable synchrotron light at BL02 in Photon Factory, KEK.

FIG. 1. (a) Crystal structure of AIB_2 . (b) Bulk and (0001) surface BZ of $AlB₂$. (c) Normal-emission EDCs in the valence-band region at $T = 40$ K measured at the photon energies of 260–450 eV. (d) ARPES intensity along the ΓA line (left), compared with the calculated band structure (right). Area enclosed by white rectangle shows the image around Γ with enhanced color contrast. (e) ARPES intensity measured along the $\Gamma K M$ and ΓM cuts (left), compared to the calculated band structure of AlB₂ (right). Red curve corresponds to the π band forming the Dirac cone. (f) Calculated band structure of MgB_2 along the Γ *K M* and ΓM cuts.

We used linearly polarized light (horizontal polarization) of 260–550 eV. The energy and angular resolutions were set to be 150 meV and 0*.*2◦, respectively. Crystals were cleaved *in situ* in an ultrahigh vacuum better than 1×10^{-10} Torr along the (0001) crystal plane. Sample temperature was kept at $T =$ 40 K during ARPES measurements. The Fermi level (E_F) of samples was referenced to that of a gold film evaporated onto the sample holder. First-principles band-structure calculations were carried out by QUANTUM ESPRESSO code with generalized gradient approximation [\[41\]](#page-4-0). The plane-wave cutoff energy and the *k*-point mesh were set to be 30 Ry and $24 \times 24 \times 12$, respectively.

We at first performed ARPES measurements along *k* cut perpendicular to the crystal surface $[\Gamma A$ cut; see Fig. $1(b)$] to elucidate the three dimensionality of electronic structure. Figure $1(c)$ shows the energy distribution curves (EDCs) at normal-emission setup measured at $T = 40$ K with various photon energies (*hν*) from 260 to 450 eV. At *hν* = 350 eV, a prominent peak is clearly observed at binding energy (E_B) of ∼5 eV, together with a weak hump at around $E_\text{B} \sim$ 14 eV. The peak rapidly disperses toward higher E_B on

increasing/decreasing *hν* from 350 eV, while the hump displays a relatively small dispersion. This distinct *hν* dependence of EDCs demonstrates that ARPES measurements with softx-ray photons are useful to elucidate the 3D electronic states of AlB_2 . To better visualize the band dispersions, we plot in Fig. $1(d)$ the ARPES intensity plotted as a function of E_B and *kz*, compared with the calculated band structure. One can immediately identify a highly dispersive band topped at ∼5 eV at the Γ point and a less dispersive band at ~14 eV, which are attributed to the B $2p \pi$ and σ_3 bands (here we label three σ bands as $\sigma_1 - \sigma_3$), respectively, as can be seen from a good agreement in the overall band dispersion between the experiment and calculation. While the calculation predicts weakly dispersive $\sigma_{1,2}$ band at ∼1 eV, the spectral weight of this band appears to be markedly suppressed in ARPES measurements probably due to the matrix-element effect of photoelectron intensity. A closer look at the Γ point with enhanced color contrast (area enclosed by white rectangle) signifies the presence of an electronlike band originating from the Al 3*s* orbital.

To see the in-plane band dispersions, we plot in Fig. $1(e)$ the ARPES intensity along the $\Gamma K M$ and ΓM cuts, measured at $hv = 340$ eV (which corresponds to the $k_z = 0$ plane). A reasonable agreement is seen between the experiment and calculation, e.g., in the highly dispersive σ_3 band with its bottom of dispersion at ∼15 eV at *-*, and the linearly dispersive π band near E_F around *K* (highlighted by red curve) which forms the Dirac-cone dispersion, as discussed later in detail. The overall spectral feature is consistent with previous ARPES results with vacuum-ultraviolet (VUV) light on AlB_2 and MgB_2 [\[42–45\]](#page-4-0). Figure 1(f) shows the calculated band structure for $MgB₂$. One immediately recognizes that the band structure is very similar between AlB_2 [right panel of Fig. 1(e)] and MgB_2 [Fig. 1(f)] except for the location of E_F . The σ_1 and σ_2 bands, which are fully occupied in AlB₂, are partially occupied in MgB₂, and the partially occupied metallic Al 3*s* band in AlB_2 is fully unoccupied in MgB_2 . This similarity and difference in the electronic band structure between AlB_2 and $MgB₂$ is reasonably explained in terms of the same crystal structure with different number of electrons; an Al atom has an extra electron in the outermost shell compared to a Mg atom. The difference in the number of valence electrons provides AlB_2 with a great advantage to observe the Dirac-cone dispersion around the *K* point by ARPES, because the Dirac cone situated near E_F in AlB₂ is pushed up far above E_F in $MgB₂$, becoming unaccessible by ARPES.

To discuss the spectral feature near E_F in more detail, we show in Fig. $2(a)$ the ARPES-intensity mapping as a function of in-plane wave vectors $(k_x \text{ and } k_y)$ at representative E_B slices in the $k_z \sim 0$ plane ($\Gamma K M$ plane) measured with 340-eV photons. At $E_B = E_F$, one can recognize a triangular intensity pattern centered at the *K* point, which is attributed to the π band. This triangular pocket originates from the Dirac-cone band with the Dirac point at ∼0.5 eV above E_F as visible from the band crossing at the *K* point in Fig. [2\(b\)](#page-2-0) [note that the crystal is slightly hole doped since the calculated Dirac point is closer to E_F , see Fig. 1(e)]. As seen in Fig. [2\(a\),](#page-2-0) the small triangular pocket at the K point gradually expands on increasing E_B with keeping its triangular shape, reflecting the band-dispersive feature of the lower Dirac cone. This suggests that the Dirac

FIG. 2. (a) ARPES-intensity mapping as a function of in-plane wave vector (k_x and k_y) at selected E_B slices, measured at $k_z \sim 0$ ($\Gamma K M$ plane) using 340-eV photons. Dashed curve is a guide to the eyes to trace the energy contours of the *π* band. (b) ARPES intensity as a function of wave vector and E_B , measured along cut A in (a). (c) Same as (a) but measured at $k_z \sim 0.8\pi$ using 290-eV photons. (d) ARPES intensity measured along cut B in (c). (e) Schematic Dirac-cone dispersion in the k_x - k_y plane at $k_z \sim 0$ (right; around the *K* point) and $\sim \pi$ (left; around the *H* point).

cone is highly anisotropic and reflects the symmetry of the *K* point (C_3) . It is noted that a similar triangular-shaped Dirac cone has been observed in doped graphene [\[46\]](#page-4-0). Such a triangular shape of Fermi surface commonly originates from the C_3 symmetry of the K point and the van Hove singularity of the band dispersion at the *M* point.

We have also mapped out the ARPES intensity as a function of in-plane wave vectors at several k_z slices. Figure $2(c)$ shows the representative energy contours at $k_z \sim 0.8\pi$ obtained with $hv = 290$ eV. One immediately recognizes that the intensity distribution is very different from that of the $k_z = 0$ plane [Fig. 2(a)] (note that the ARPES intensity at $k_z \sim \pi$ was found to be very weak and the energy contour cannot be accurately discussed). This is reasonable since AlB_2 has a sizable k_z dispersion [see Fig. $1(d)$], and the Dirac point is located well below E_F ($E_B \sim 4$ eV) in this k_z slice, as visible from the band dispersion in Fig. $2(d)$. Since the upper Dirac cone touches another Dirac cone located at the adjacent K point well above the Dirac point, the energy contour at E_F no longer shows a closed triangular pattern, but exhibits an open arclike pattern with no E_F crossing of band on the *KM* cut. On increasing E_B , this open contour gradually shrinks toward the \bar{K} point, finally converting into a Dirac point at $E_B \sim 4$ eV (note that there are several other bands that complicate the intensity pattern). Such behavior is schematically illustrated in Fig. $2(e)$.

To elucidate how the Dirac-cone band disperses along the k_z direction, we show in Fig. [3\(a\)](#page-3-0) the ARPES intensity across the *K* point measured at various k_z 's, together with the corresponding second-derivative intensity plots [Fig. [3\(b\)\]](#page-3-0). In Figs. $3(a)$ and $3(b)$, we observe a linearly dispersive band for all the *kz* slices. The Dirac point located at ∼0*.*5 eV above *E*^F at $k_z \sim 0$ gradually moves downward on increasing k_z and finally reaches 5 eV below E_F at $k_z \sim \pi$. Intriguingly, the band always

keeps the degeneracy at the \bar{K} point irrespective of k_z with no indication of energy-gap opening. This firmly establishes the presence of a DNL along the whole KH line in AlB_2 . The DNL has a finite slope in the $E-k_z$ space due to the k_z dispersion of the π band, as illustrated in Fig. [3\(c\).](#page-3-0) It is noted that we surveyed the electronic states over the entire BZ and found no evidence for the existence of other DNLs in AlB_2 . This is reasonable since the Dirac cone exists only around the \overline{K} point, as recognized from Fig. [1\(e\).](#page-1-0)

Now we discuss characteristics of the observed DNL in AlB2. The observed Dirac-cone band responsible for the DNL originates from the π band associated with the honeycomb B layer, which is the same situation as graphene showing the Dirac-cone band with the C-2 $p \pi$ character. It was theoretically predicted that when graphene stacks with AA sequence, the Dirac point always keeps the degeneracy irrespective of k_z and forms the DNL along the *KH* line [\[39\]](#page-4-0) since the sublattice symmetry is preserved in such multilayer graphene. Unfortunately, this situation is not realized in actual graphene since multilayer graphene (graphite) usually stacks with AB or ABC sequence. On the other hand, the honeycomb boron layer in AlB_2 stacks with AA sequence, possibly leading to the emergence of DNL in AlB_2 . However, one may concern that such DNL is easily gapped by the spin-orbit interaction (unless the band degeneracy is protected by nonsymmorphic symmetry), as demonstrated in the gap opening in silicene and germanene [\[47\]](#page-4-0). But, in the case of AlB_2 , the SOC is extremely weak (in the level of *μ*eV by referring to the atomic SOC value of boron [\[40\]](#page-4-0)), so that such a problem is overcome, making $AlB₂$ an ideal material to study the behavior of DNL.

It is inferred that the observed DNL in $AlB₂$ has the same origin as that recently predicted for MgB_2 [\[40\]](#page-4-0), because both materials have essentially the same crystal structure and

FIG. 3. (a) and (b) ARPES intensity and corresponding second-derivative intensity plots, respectively, measured along a cut crossing the \bar{K} point for selected *kz*'s. Arrows indicate location of the Dirac points. (c) Schematic of the Dirac-cone dispersion and DNL around the *KH* line.

consequently the same band structure except for the position of the chemical potential (Fermi level) due to the difference in the number of valence electrons (Al has one additional electron compared to Mg). It is therefore suggested that $MgB₂$ also has a DNL and may behave as topological superconductor with nodal fermions contributing to the superconducting pairing. It is noted here that $AIB₂$ is a suitable system to investigate the anomalous transport properties originating from nonzero Berry phase, because it is theoretically proposed that the Landau orbit enclosing the *KH* line gives rise to the nonzero Berry phase $[40]$. This condition is exactly satisfied in AlB_2 [see Fig. $2(a)$] but not in MgB₂. Moreover, by tuning the Al/Mg ratio in the $(AI, Mg)B₂$ alloy, we are able to systematically control the electronic phase between the superconducting phase and the nontrivial Berry phase without breaking the DNL. The $(A1,Mg)B₂$ system would provide a precious opportunity to investigate the relationship between topological superconductivity and Berry phase.

Finally, we briefly comment on the relationship between the present results and recent studies on isostructural compounds $TiB₂$ and $ZrB₂$. It has been reported by the first-principles band calculations and ARPES that these compounds have three different types of nodal structures (nodal net) originating from the Ti-3*d*/Zr-4*d* electrons [\[30–32\]](#page-4-0) in contrast to the simple DNL in $AlB₂$ originating from the B-2 p electrons. While the nodal net of $TiB₂/ZrB₂$ is associated with mirror symmetry together with time-reversal and space-inversion symmetry (*PT* symmetry), the DNL of $AIB₂$ is characterized by the sublattice symmetry

of honeycomb B layer and *PT* symmetry. Therefore, the electronic states associated with the nodal fermions and related symmetries are very different between AlB_2 and $(\text{Ti/Zr})\text{B}_2$, although they share the same crystal structure. The AlB_2 -type layered diborides would thus serve as an excellent platform to explore a rich variety of nodal fermions and their relationship to symmetries.

In summary, we performed ARPES experiments of AIB_2 with bulk-sensitive soft-x-ray photons, and determined the 3D band structure and Fermi surface. We found a triangularshaped Dirac-cone dispersion at the *K* point of bulk BZ in the $k_x - k_y$ plane. The Dirac cone significantly disperses along the k_z direction while keeping the band degeneracy at the \bar{K} point of surface BZ, producing a characteristic DNL associated with the combination of *PT* symmetry and sublattice symmetry of honeycomb B layer. The present result paves a pathway toward investigating the exotic nodal structures in weakly spin-orbit-coupled topological materials.

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